



# SN75LP1185 LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

SLLS335A – JANUARY 1999 – REVISED JANUARY 2001

## AVAILABLE OPTIONS

T <sub>A</sub>	PACKAGED DEVICES		
	PLASTIC SHRINK SMALL-OUTLINE (DB)	PLASTIC SMALL OUTLINE (DW)	PLASTIC DIP (N)
0°C to 70°C	SN75LP1185DBR	SN75LP1185DW	SN75LP1185N

The DB package is only available taped and reeled. The DW package also is available taped and reeled. Add the suffix R to device type (e.g., SN75LP1185DWR).

## Function Tables

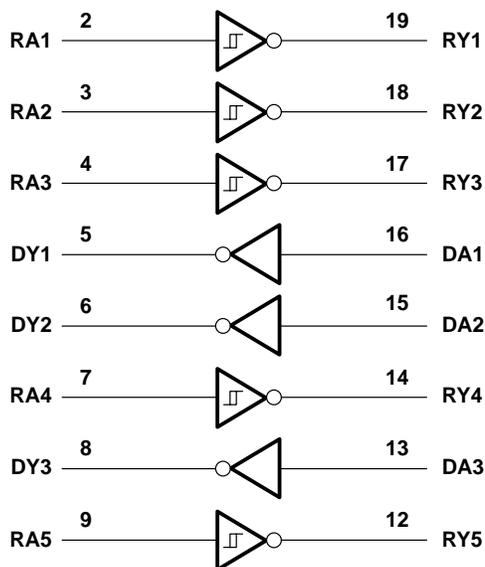
### DRIVER

INPUT DA	OUTPUT DY
H	L
L	H
Open	L

### RECEIVER

INPUT RA	OUTPUT RY
H	L
L	H
Open	H

## logic diagram (positive logic)



# SN75LP1185

## LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Positive supply-voltage range (see Note 1): $V_{CC}$ .....	–0.5 V to 7 V
$V_{DD}$ .....	–0.5 V to 15 V
Negative supply-voltage range, $V_{SS}$ (see Note 1) .....	0.5 V to –15 V
Input-voltage range, $V_I$ : Receiver (RA) .....	–30 V to 30 V
Driver (DA) .....	–0.5 V to $V_{CC} + 0.4$ V
Output-voltage range, $V_O$ : Receiver (RY) .....	–0.5 V to 6 V
Driver (DY) .....	–15 V to 15 V
Electrostatic discharge: Bus pins (human-body model) (see Note 2) .....	Class 3: 15 kV
Bus pins (machine model) .....	500 V
All pins (human-body model) (see Note 2) .....	Class 3: 5 kV
All pins (machine model) .....	400 V
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package .....	70°C/W
DW package .....	58°C/W
N package .....	69°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds .....	260°C
Storage temperature range, $T_{stg}$ .....	65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to network ground terminal, unless otherwise noted.  
 2. Per MIL-STD-883, Method 3015.7  
 3. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions

		MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage (see Note 4)	4.75	5	5.25	V
$V_{DD}$	Supply voltage (see Note 5)	9	12	15	V
$V_{SS}$	Supply voltage (see Note 5)	–9	–12	–15	V
$V_{IH}$	High-level input voltage		2		V
$V_{IL}$	Low-level input voltage			0.8	V
$V_I$	Receiver input voltage		–25	25	V
$I_{OH}$	High-level output current			–1	mA
$I_{OL}$	Low-level output current			2	mA
$T_A$	Operating free-air temperature		0	70	°C

- NOTES: 4.  $V_{CC}$  cannot be greater than  $V_{DD}$ .  
 5. The device operates down to  $V_{DD} = V_{CC}$  and  $|V_{SS}| = V_{CC}$ , but supply currents increase and other parameters may vary slightly from the data sheet limits.



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### supply currents over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply current for $V_{CC}$ , $I_{CC}$	$V_{DD} = 9\text{ V}$ , $V_{SS} = -9\text{ V}$			1000	$\mu\text{A}$
	$V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$			1000	
Supply current for $V_{DD}$ , $I_{DD}$	No load, All inputs at minimum $V_{OH}$ or maximum $V_{OL}$	$V_{DD} = 9\text{ V}$ , $V_{SS} = -9\text{ V}$		800	
		$V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$		800	
Supply current for $V_{SS}$ , $I_{SS}$		$V_{DD} = 9\text{ V}$ , $V_{SS} = -9\text{ V}$		-625	
		$V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$		-625	

### driver electrical characteristics over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$V_{OH}$ High-level output voltage	$V_{IL} = 0.8\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1	$V_{DD} = 9\text{ V}$ , $V_{SS} = -9\text{ V}$	5	5.8	6.6	V
		$V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$ , See Note 6	5	5.8	6.6	
$V_{OL}$ Low-level output voltage	$V_{IH} = 2\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1	$V_{DD} = 9\text{ V}$ , $V_{SS} = -9\text{ V}$	-5	-5.8	-6.9	V
		$V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$ , See Note 6	-5	-5.9	-6.9	
$I_{IH}$ High-level input current	$V_I$ at $V_{CC}$			1	$\mu\text{A}$	
$I_{IL}$ Low-level input current	$V_I$ at GND			-1	$\mu\text{A}$	
$I_{OS(H)}$ Short-circuit high-level output current	$V_O = \text{GND}$ or $V_{SS}$ . See Figure 2 and Note 7		-30	-55	mA	
$I_{OS(L)}$ Short-circuit low-level output current	$V_O = \text{GND}$ or $V_{DD}$ . See Figure 2 and Note 7		30	55	mA	
$r_o$ Output resistance	$V_{DD} = V_{SS} = V_{CC} = 0$ , $V_O = 2\text{ V}$	300			$\Omega$	

NOTES: 6. Maximum output swing is clamped nominally at  $\pm 6\text{ V}$  to enable the higher data rates associated with this device and to reduce EMI emissions. The driver outputs may slightly exceed the maximum output voltage over the full  $V_{CC}$  and temperature ranges.  
7. Not more than one output should be shorted at one time.



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## LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### driver switching characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
$t_{PHL}$	Propagation delay time, high- to low-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$ , See Figure 1	300	800	1600	ns		
$t_{PLH}$	Propagation delay time, low- to high-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$ , See Figure 1	300	800	1600	ns		
$t_{TLH}$	Transition time, low- to high-level output	$V_{CC} = 5\text{ V}$ , $V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$ , $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , See Figure 1 and Note 9	Using $V_{TR} = 10\%$ -to- $90\%$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$ , See Note 8		375	2240	ns	
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$		200	1500		
			Using $V_{TR} = \pm 2\text{ V}$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$		133	1000		
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = $125\text{ kbit/s}$ , $C_L = 2500\text{ pF}$			2750		
$t_{THL}$	Transition time, high- to low-level output	$V_{CC} = 5\text{ V}$ , $V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$ , $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , See Figure 1 and Note 9	Using $V_{TR} = 10\%$ -to- $90\%$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$ , See Note 8		375	2240	ns	
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$		200	1500		
			Using $V_{TR} = \pm 2\text{ V}$ transition region, Driver speed = $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$		133	1000		
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = $125\text{ kbit/s}$ , $C_L = 2500\text{ pF}$			2750		
SR	Output slew rate	$V_{CC} = 5\text{ V}$ , $V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$	Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = $0$ to $250\text{ kbit/s}$ , $C_L = 15\text{ pF}$		4	20	30	V/ $\mu\text{s}$

NOTES: 8. Equivalent to the SN75C185. The SN75LP1185 output-voltage swing is clamped to about 70% of the typical SN75C185 output-voltage swing, and the specified limits reflect the reduced output swing.

9. Maximum output swing is limited to  $\pm 6\text{ V}$  to enable the higher data rates associated with this device and to reduce EMI emissions.

### receiver electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IT+}$	Positive-going input threshold voltage	See Figure 3	1.6	2	2.55	V
$V_{IT-}$	Negative-going input threshold voltage	See Figure 3	0.6	1	1.45	V
$V_{HYS}$	Input hysteresis, $V_{IT+} - V_{IT-}$	See Figure 3	600	1000		mV
$V_{OH}$	High-level output voltage	$I_{OH} = -1\text{ mA}$	2.5	3.9		V
$V_{OL}$	Low-level output voltage	$I_{OL} = 2\text{ mA}$		0.33	0.5	V
$I_{IH}$	High-level input current	$V_I = 3\text{ V}$	0.43	0.6	1	mA
		$V_I = 25\text{ V}$	3.6	5.1	8.3	
$I_{IL}$	Low-level input current	$V_I = -3\text{ V}$	-0.43	-0.6	-1	mA
		$V_I = -25\text{ V}$	-3.6	-5.1	-8.3	
$I_{OS(H)}$	Short-circuit high-level output current	$V_O = 0$ , See Figure 5 and Note 7			-20	mA
$I_{OS(L)}$	Short-circuit low-level output current	$V_O = V_{CC}$ , See Figure 5 and Note 7			20	mA
$R_{IN}$	Input resistance	$V_I = \pm 3\text{ V}$ to $\pm 25\text{ V}$	3	5	7	k $\Omega$

NOTE 7: Not more than one output should be shorted at one time.



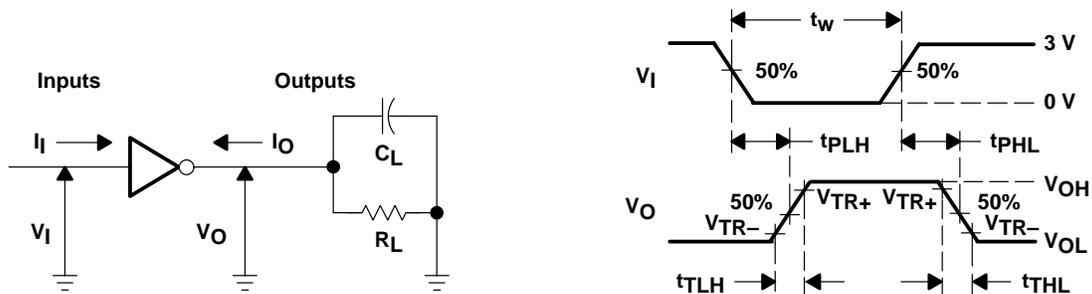
# SN75LP1185 LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

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receiver switching characteristics over recommended operating free-air temperature range,  $C_L = 50$  pF (unless otherwise noted) (see Figure 4)

PARAMETER		MIN	TYP	MAX	UNIT
$t_{PHL}$	Propagation delay time, high- to low-level output		400	900	ns
$t_{PLH}$	Propagation delay time, low- to high-level output		400	900	ns
$t_{TLH}$	Transition time, low- to high-level output		200	500	ns
$t_{THL}$	Transition time, high- to low-level output		200	400	ns
$t_{SK(p)}$	Pulse skew $ t_{PLH} - t_{PHL} $		200	425	ns

## PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics:  
 For  $C_L < 1000$  pF:  $t_w = 4$   $\mu$ s, PRR = 250 kbit/s,  $Z_O = 50$   $\Omega$ ,  $t_r$  and  $t_f < 50$  ns.  
 For  $C_L = 2500$  pF:  $t_w = 8$   $\mu$ s, PRR = 125 kbit/s,  $Z_O = 50$   $\Omega$ ,  $t_r$  and  $t_f < 50$  ns.  
 B.  $C_L$  includes probe and jig capacitance.

Figure 1. Driver Parameter Test Circuit and Waveform

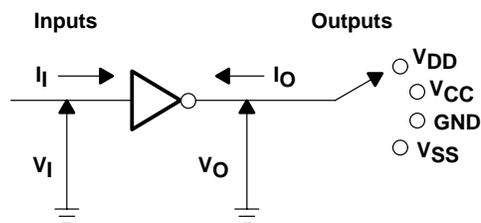


Figure 2. Driver  $I_{OS}$  Test

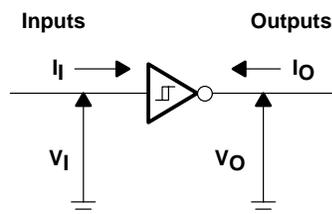
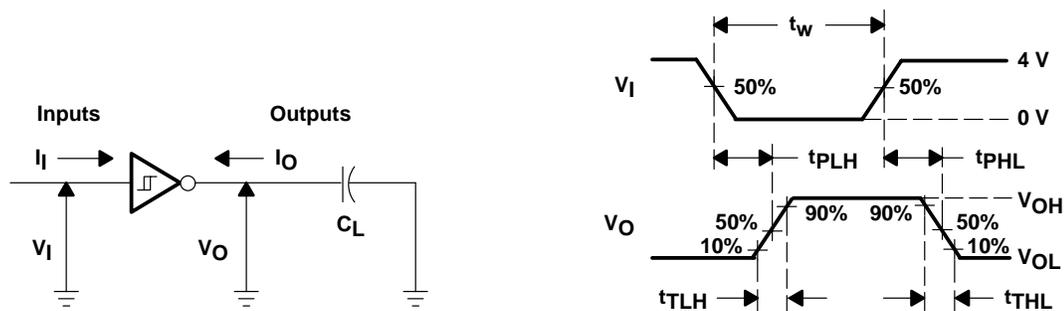


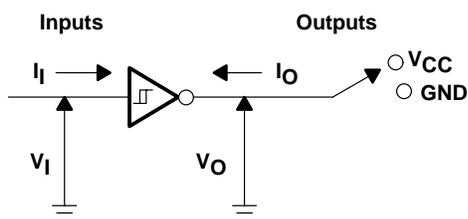
Figure 3. Receiver  $V_{IT}$  Test

**PARAMETER MEASUREMENT INFORMATION**



NOTES: A. The pulse generator has the following characteristics:  $t_w = 4 \mu\text{s}$ , PRR = 250 kbit/s,  $Z_O = 50 \Omega$ ,  $t_r$  and  $t_f < 50 \text{ ns}$ .  
B.  $C_L$  includes probe and jig capacitance.

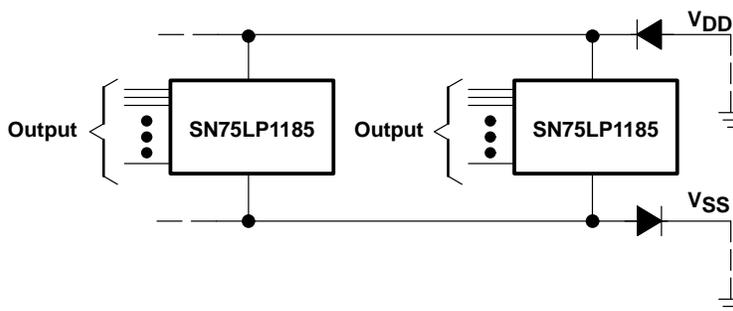
**Figure 4. Receiver Parameter Test Circuit and Waveform**



**Figure 5. Receiver  $I_{OS}$  Test**

**APPLICATION INFORMATION**

Diodes placed in series with the  $V_{DD}$  and  $V_{SS}$  leads protect the SN75LP1185 in the fault condition when the device outputs are shorted to  $\pm 15 \text{ V}$  and the power supplies are at low voltage and provide low-impedance paths to ground (see Figure 6).



**Figure 6. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F**

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
SN75LP1185DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	5LP1185	<a href="#">Samples</a>
SN75LP1185DBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	5LP1185	<a href="#">Samples</a>
SN75LP1185DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	5LP1185	<a href="#">Samples</a>
SN75LP1185DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75LP1185	<a href="#">Samples</a>
SN75LP1185N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75LP1185N	<a href="#">Samples</a>
SN75LP1185NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75LP1185N	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

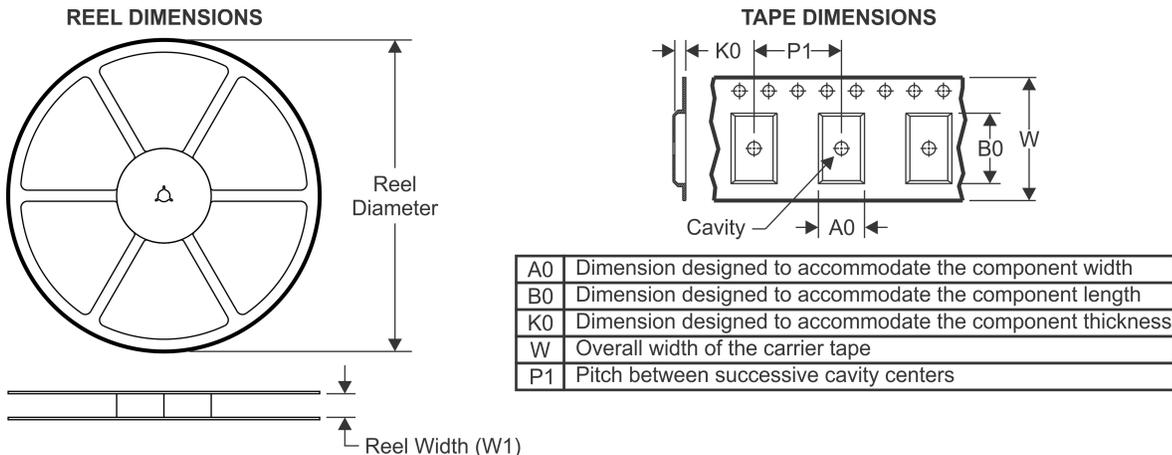
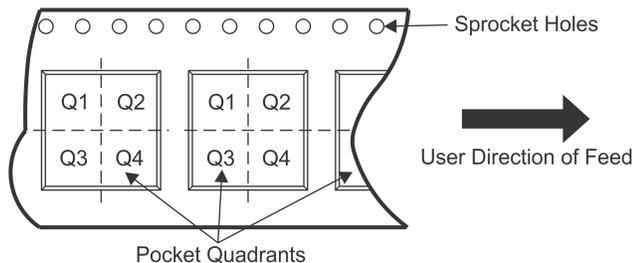
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LP1185DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN75LP1185DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

**TAPE AND REEL BOX DIMENSIONS**

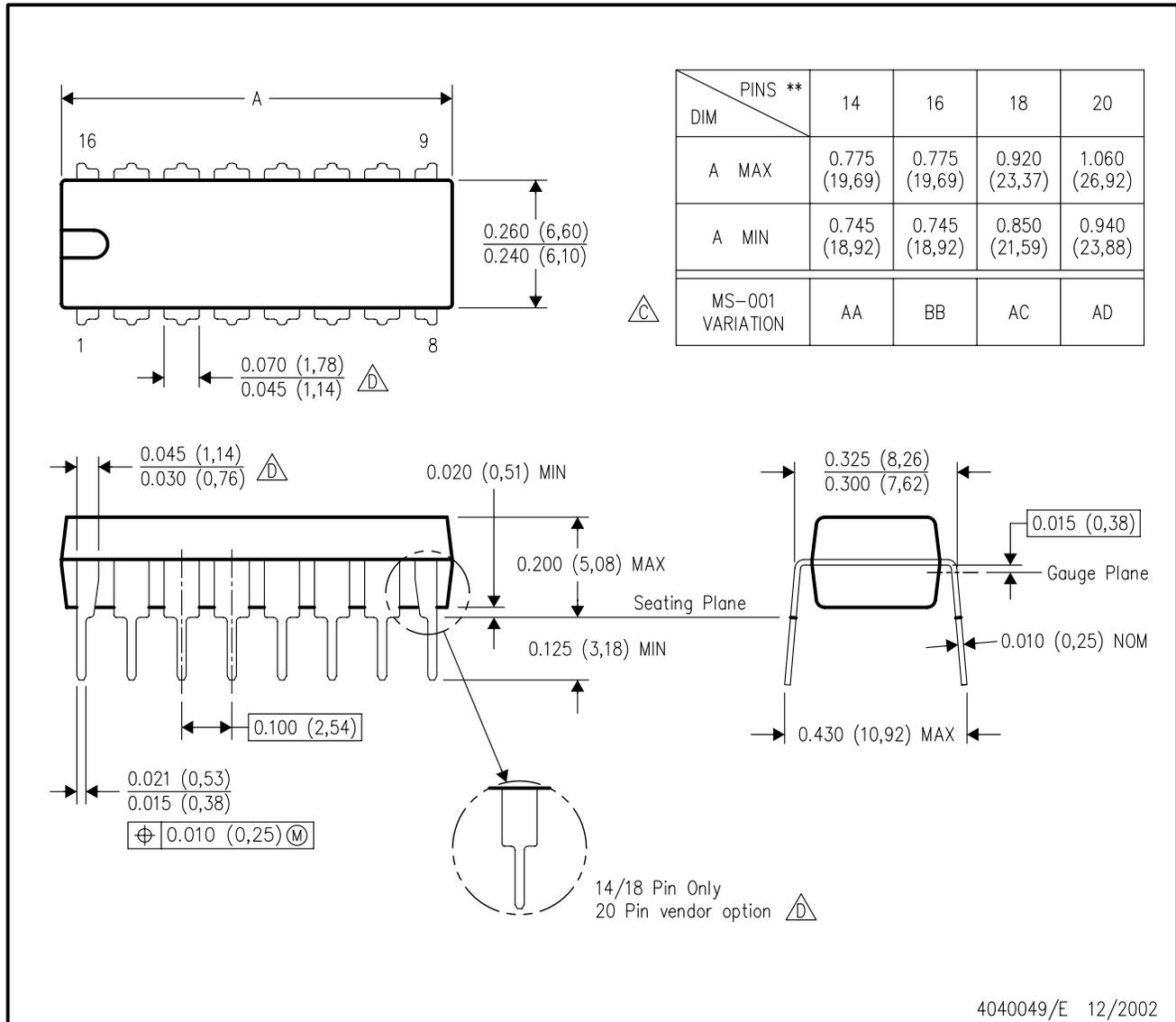

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75LP1185DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN75LP1185DWR	SOIC	DW	20	2000	367.0	367.0	45.0

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

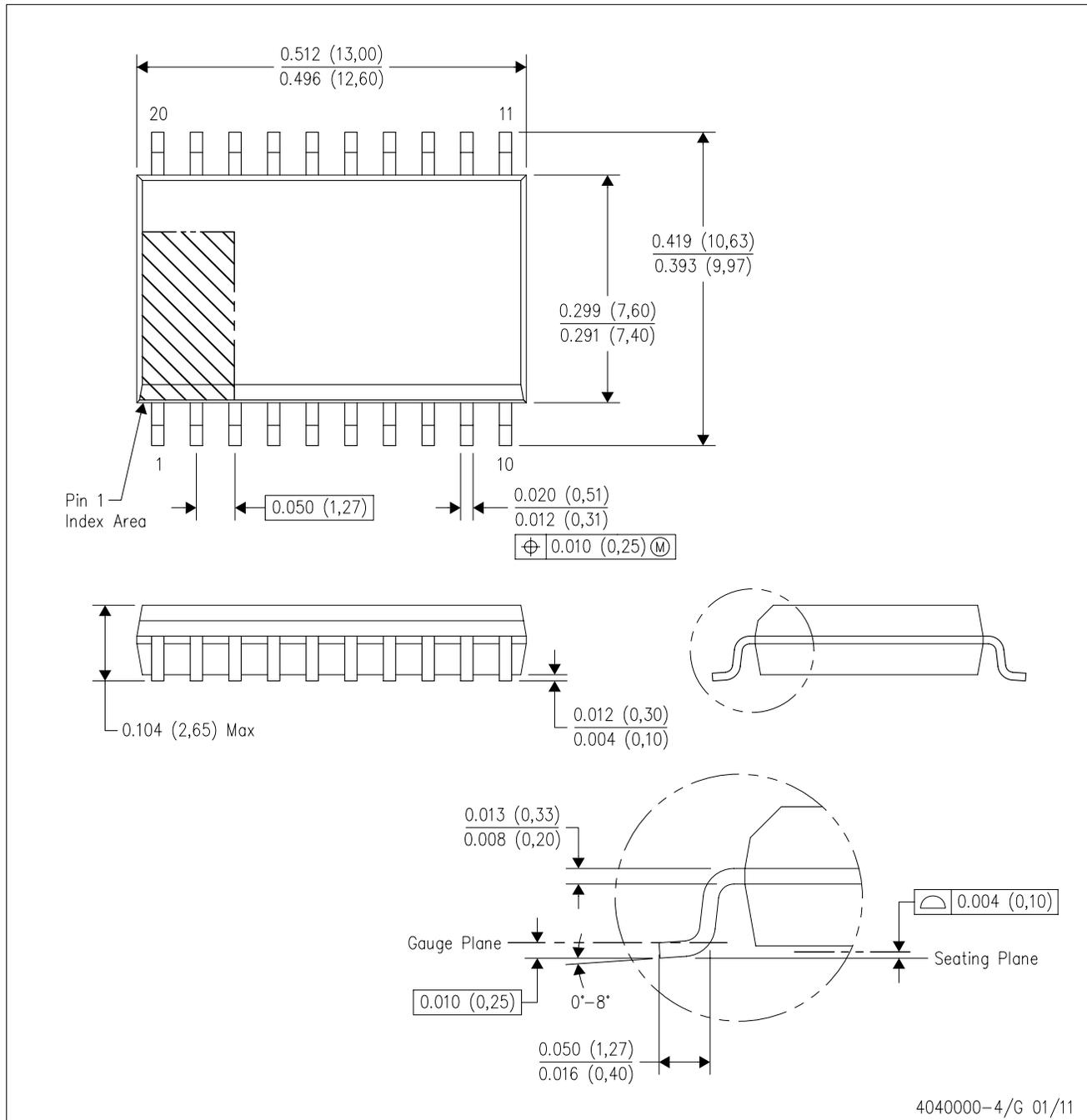


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- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - (C) Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - (D) The 20 pin end lead shoulder width is a vendor option, either half or full width.

DW (R-PDSO-G20)

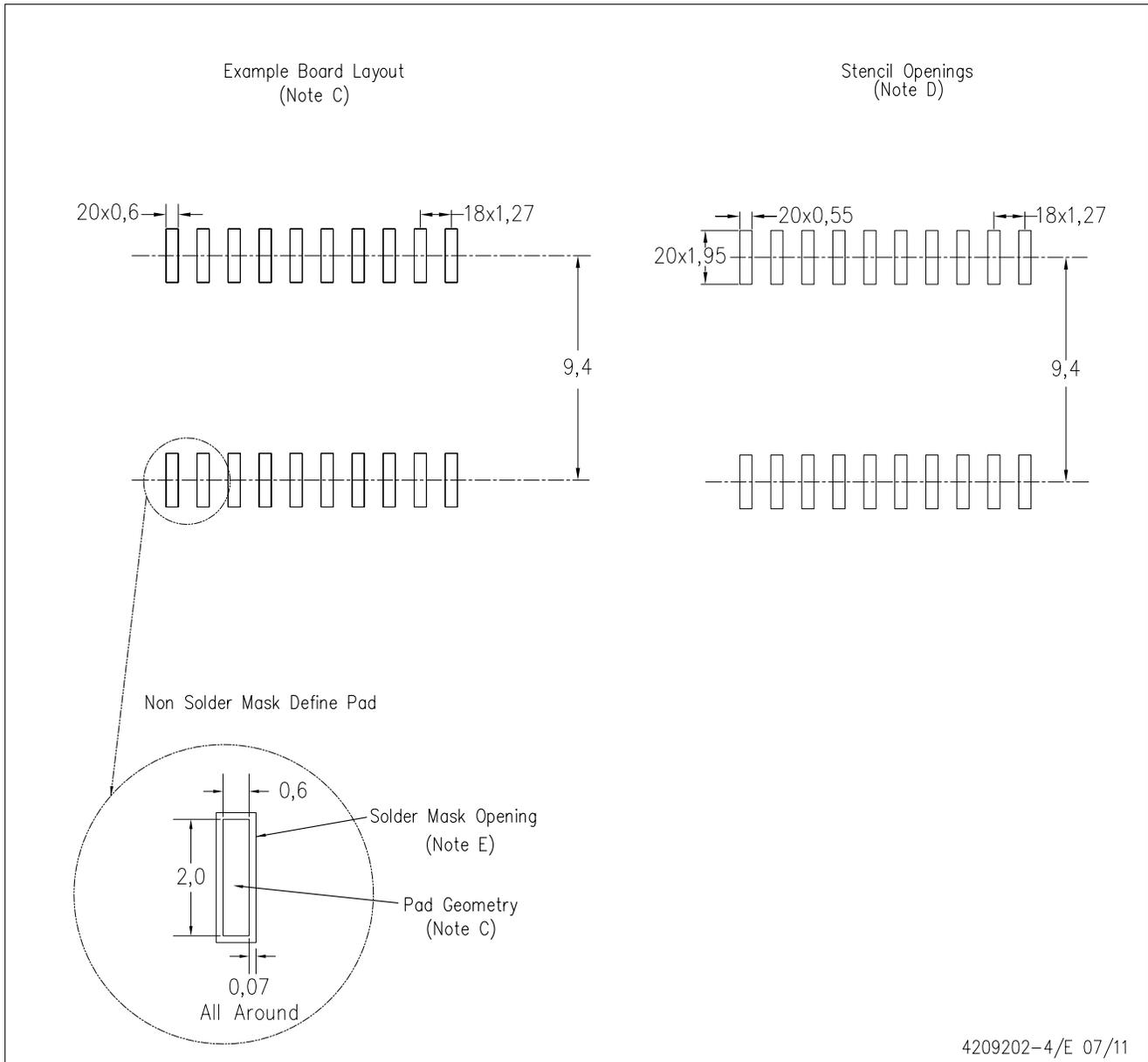
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AC.

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



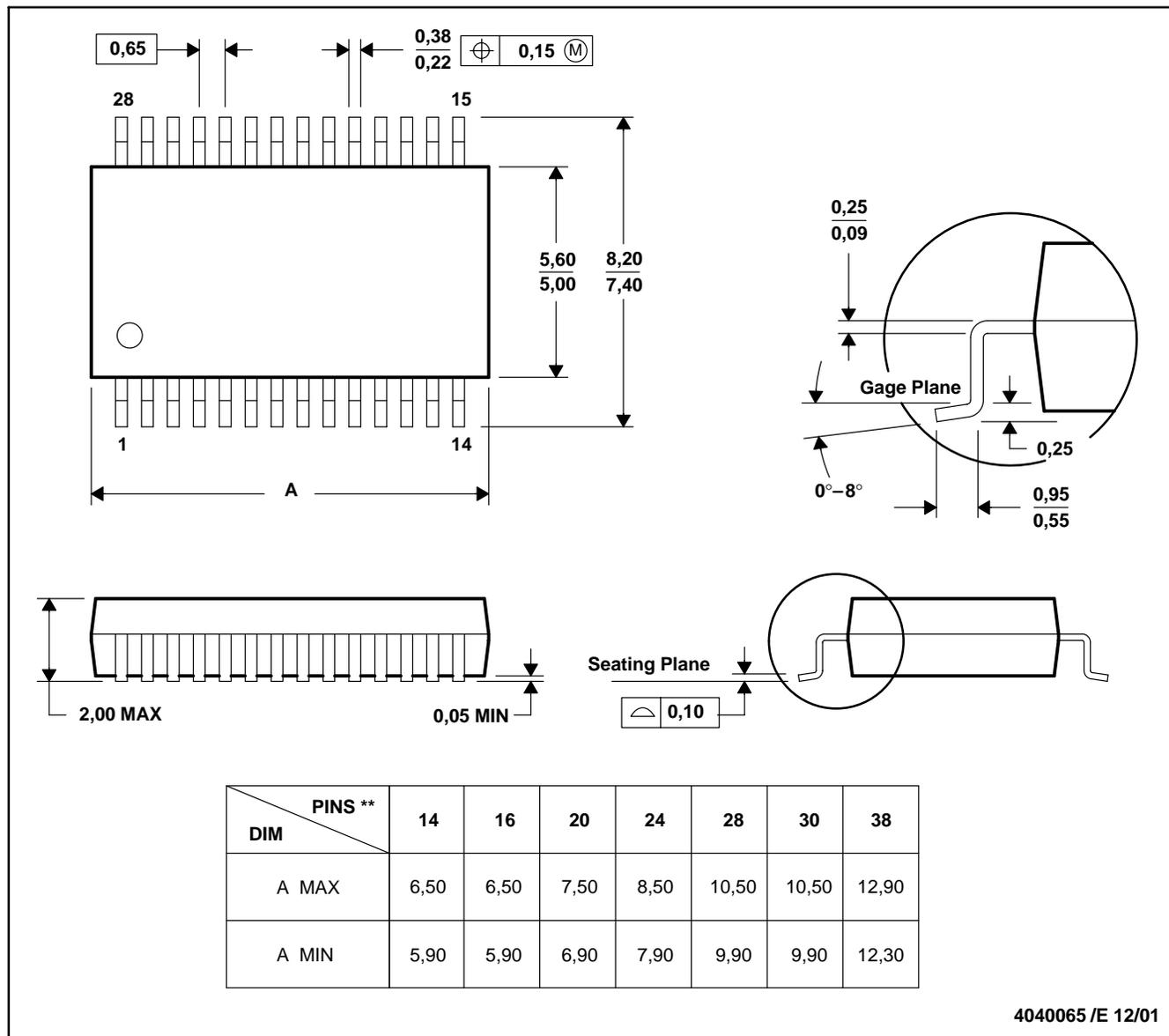
4209202-4/E 07/11

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Refer to IPC7351 for alternate board design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150

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